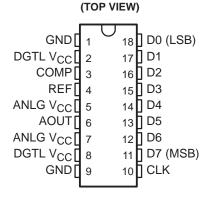
N PACKAGE

- 8-Bit Resolution
- ±0.2% Linearity
- Maximum Conversion Rate . . . 30 MHZ Typ 20 MHz Min
- Analog Output Voltage Range
 V_{CC} to V_{CC} -1 V
- TTL Digital Input Voltage
- 5-V Single-Supply Operation
- Low Power Consumption . . . 250 mW Typ
- Interchangeable With Fujitsu MB40778

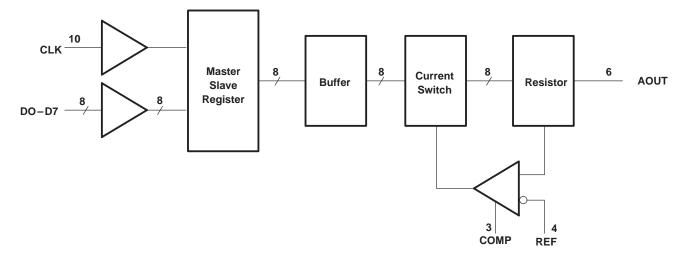
description



The TL5602 is a low-power ultra-high-speed video digital-to-analog converter that uses the Advanced Low-Power Schottky (ALS) process. It converts digital signals to analog signals at a sampling rate of dc to 20 MHz. Because of such high-speed capability, the TL5602 is suitable for digital video applications such as digital television, video processing with a computer, and radar signal processing.

The TL5602C is characterized for operation from 0°C to 70°C.

functional block diagram

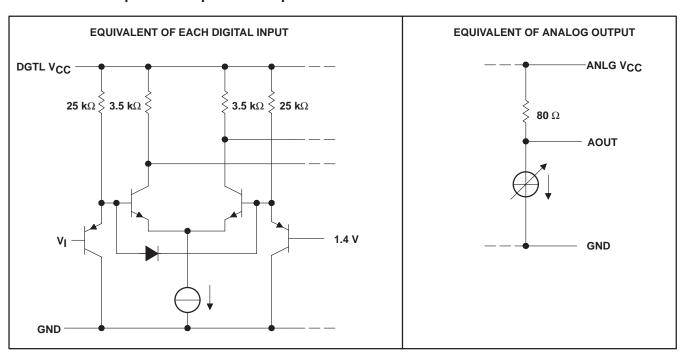


FUNCTION TABLE

STEP	DIGITAL INPUTS						OUTPUT		
SIEF	D7	D6	D5	D4	D3	D2	D1	D0	VOLTAGE [†]
0	L	L	L	L	L	L	L	L	3.980 V
1	L	L	L	L	L	L	L	L	3.984 V
					1				I
127	L	Н	Н	Н	Н	Н	Н	Н	4.488 V
128	Н	L	L	L	L	L	L	L	4.492 V
129	Н	L	L	L	L	L	L	Н	4.496 V
					1				I
254	Н	Н	Н	Н	Н	Н	Н	L	4.996 V
255	Н	Н	Н	Н	Н	Н	Н	Н	5.000 V

† For V_{CC} = 5 V, V_{ref} = 3.976 V

schematics of equivalent input and output circuits



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, ANLG V _{CC} , DGTL V _{CC}	V to 7 V
Digital input voltage range, V ₁ –0.5	V to 7 V
Analog reference voltage range, V _{ref}	C +0.5 V
Operating free-air temperature range 0°C	to 70°C
Storage temperature range –55°C t	to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	. 260°C



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recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.75	5	5.25	V
Analog reference voltage, V _{ref} (see Note 1)	3.8	4	4.2	V
High-level input voltage, VIH	2			V
Low-level input voltage, V _{IL}			0.8	V
Pulse duration, CLK high or low, t _W	25			ns
Setup time, data before CLK↑, t _{SU}	12.5			ns
Hold time, data after CLK↓, th	12.5			ns
Phase compensation capacitance, C _{comp} (see Note 2)	1			μF
Operating free-air temperature, T _A	0		70	°C

NOTES: 1. $V_{CC} - V_{ref} \le 1.2 \text{ V}$

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CO	MIN	TYP†	MAX	UNIT	
lį	Input current at maximum input voltage	$V_{CC} = 5.25 \text{ V},$	V _I = 7 V		0	100	μΑ
lιΗ	High-level input current	$V_{CC} = 5.25 \text{ V},$	V _I = 2.7 V		0	20	μΑ
Ι _Ι L	Low-level input current	$V_{CC} = 5.25 \text{ V},$	V _I = 0.4 V		-40	- 400	μΑ
I _{ref}	Input reference current	V _{Iref} = 4 V				10	μΑ
VFS	Full-scale analog output voltage	V _C C = 5 V,	$V_{ref} = 3.976 V$,	V _{CC} -15	Vcc	V _{CC} +15	mV
Vzs	Zero-scale analog output voltage	$I_O = 0$ (no load)		3.919	3.980	4.042	111 V
z _O	Output impedance	T _A = 25°C		70	80	90	Ω
ICC	Supply current	V _{ref} = 4.05 V			50	75	mA

 $[\]dagger$ All typical values are at $V_{CC} = 5 \text{ V}$, $V_{ref} = 4 \text{ V}$, $T_A = 25^{\circ}C$.

operating characteristics over recommended ranges of supply voltage and operating free-air temperature

PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
EL	Linearity error				±0.2	%FSR
f _{max}	Maximum converstion rate		20	30		MHz

^{2.} This capacitor should be connected between COMP and GND.

PARAMETER MEASUREMENT INFORMATION

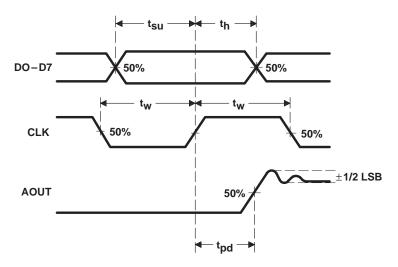


Figure 1. Voltage Waveforms

TYPICAL CHARACTERISTICS

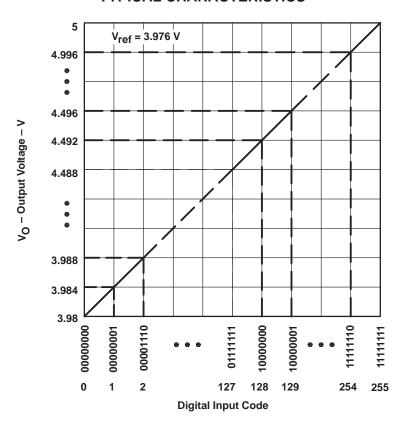


Figure 2. Ideal Conversion Characteristics



TYPICAL CHARACTERISTICS

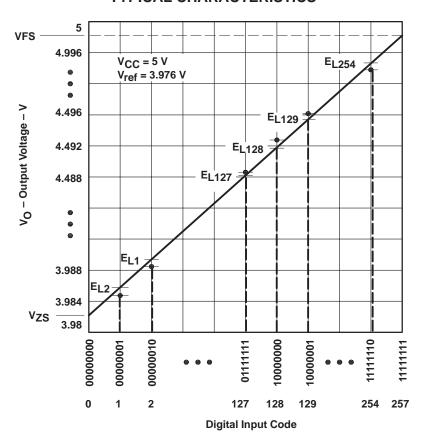


Figure 3. End-Point Linearity Error

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